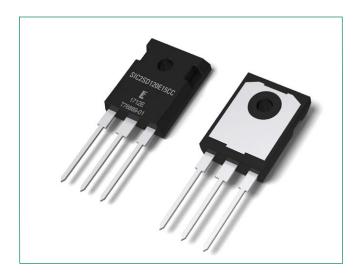
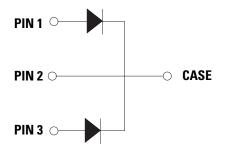
GEN2 SiC Schottky Diode LSIC2SD120E15CC, 1200 V, 15 A, T0-247-3L

LSIC2SD120E15CC





Circuit Diagram TO247-3L



Description

This series of silicon carbide (SiC) Schottky diodes has negligible reverse recovery current, high surge capability, and a maximum operating junction temperature of 175 °C. These diodes series are ideal for applications where improvements in efficiency, reliability, and thermal management are desired.

Features

- Positive temperature coefficient for safe operation and ease of paralleling
- 175 °C maximum operating junction temperature
- Excellent surge capability
- Extremely fast, temperature-independent switching behavior
- Dramatically reduced switching losses compared to Si bipolar diodes

Applications

- Boost diodes in PFC or DC/DC stages
- Switch-mode power supplies
- Uninterruptible power supplies
- Solar inverters
- Industrial motor drives
- EV charging stations

Environmental

• Littelfuse "RoHS" logo = RoHS RoHS conform



• Littelfuse "PB-free" logo = Pb-free lead plating



Maximum Ratings

Characteristics	Symbol	Conditions	Value	Unit	
Repetitive Peak Reverse Voltage	V _{RRM}	-	1200	V	
DC Blocking Voltage	V _R	T _j = 25 °C	1200	V	
	l _F	T _c = 25 °C	24.5/49	А	
Continuous Forward Current (Per Leg/Device)		T _c = 135 °C	12/24		
(. c. 20g, 2 c. 100,		T _c = 154 °C	8/16		
Non-Repetitive Forward Surge Current (Per Leg)	FSM	$T_{\rm C} = 25 {\rm ^{\circ}C}$, $T_{\rm p} = 10 {\rm ms}$, Half sine pulse	65	А	
Power Dissipation	D	T _c = 25 °C	125/250	W	
(Per Leg/Device)	P _{Tot}	T _c = 110 °C	54/108		
Operating Junction Temperature	T	-	-55 to 175	°C	
Storage Temperature	T _{STG}	-	-55 to 150	°C	
Soldering Temperature	T _{sold}	-	260	°C	

GEN2 SiC Schottky Diode LSIC2SD120E15CC, 1200 V, 15 A, T0-247-3L

Electrical Characteristics (Per Leg)

Characteristics Symbol	Combal	Conditions	Value			11	
Characteristics	Symbol	Conditions	Min.	Тур.	Max.	Unit	
Forward Voltage	V	I _F = 8 A, T _J = 25 °C	-	1.5	1.8	V	
	V _F	I _F = 8 A, T _J = 175 °C	-	2.2	-		
Reverse Current		V _R = 1200 V , T _J = 25 °C	-	<1	100		
	I _R	V _R = 1200 V , T _J = 175 °C	-	10		μΑ	
Total Capacitance (V _R = 1 V, f =1 MHz	-	454	-		
	С	V _R = 400 V, f = 1 MHz	-	45	-	pF	
		V _R = 800 V, f = 1 MHz	-	33	-		
Total Capacitive Charge	Q _c	$V_{R} = 800 \text{ V}, \ Q_{c} = \int_{C}^{V_{R}} C(V) dV$	-	47	-	nC	

Footnote: T₁ = +25 °C unless otherwise specified

Thermal Characteristics

Characteristics	Symbol Conditions		Value			Unit
Characteristics	Symbol	Conditions	Min.	Тур.	Max.	Omit
Thermal Resistance (Per Device/Leg)	R _{euc}	-	-	1.2/0.6	-	°C/W

Figure 1: Typical Foward Characteristics (Per Leg)

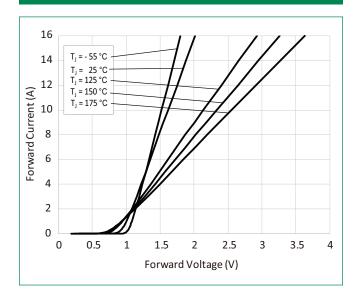


Figure 2: Typical Reverse Characteristics (Per Leg)

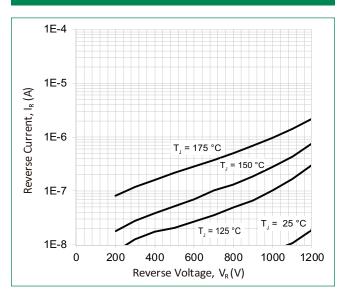




Figure 3: Power Derating (Per Leg)

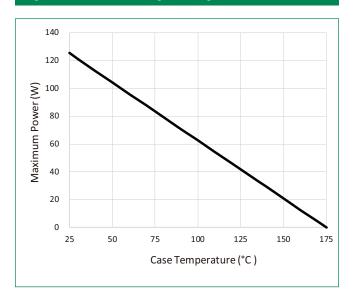


Figure 4: Current Derating (Per Leg)

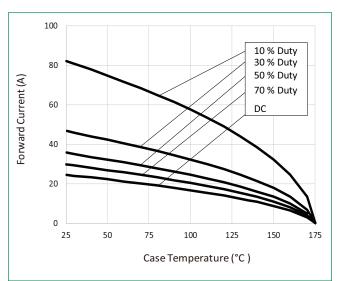


Figure 5: Capacitance vs. Reverse Voltage (Per Leg)

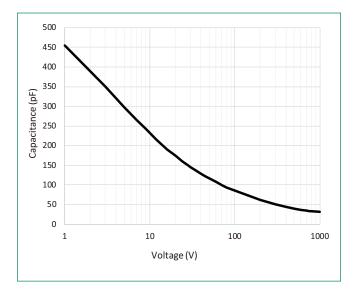


Figure 6: Capacitive Charge vs. Reverse Voltage (Per Leg)

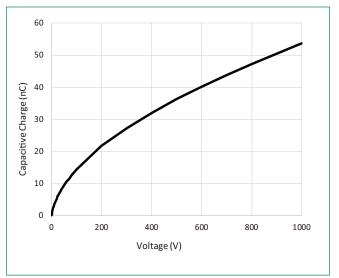


Figure 7: Stored Energy vs. Reverse Voltage (Per Leg)

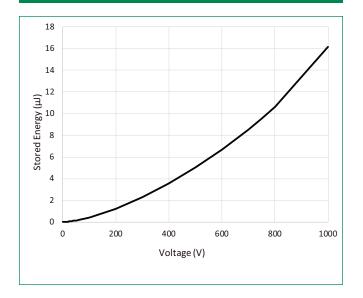
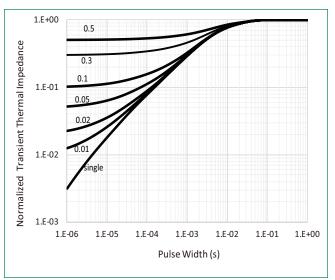
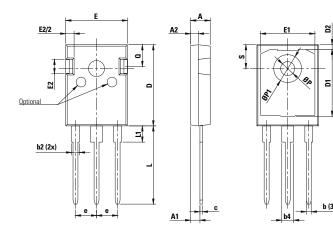


Figure 8: Transient Thermal Impedance (Per Device)



Package Dimensions TO-247-3L

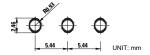


Symbol	Millimeters					
Syllibol	Min	Nom	Max			
Α	4.80	5.03	5.20			
A1	2.25	2.38	2.54			
A2	1.85	1.98	2.11			
b	0.99	-	1.40			
b2	1.65	-	2.39			
b4	2.59	-	3.43			
С	0.38	0.64	0.89			
D	20.80	20.96	21.34			
D1	13.50	-	-			
D2	0.51	1.19	1.35			
е	5.44 BSC					
E	15.75	15.90	16.13			
E1	13.06	14.02	14.15			
E2	4.19	4.32	4.83			
L	19.81	20.19	20.57			
L1	3.81	4.19	4.45			
øΡ	3.55	3.61	3.66			
øP1	7.06	7.19	7.32			

5.61

6.17

Recommended Hole Pattern Layout



Votes:

- Dimensions are in millimeters
 Dimension D, E do not include mold flash. Mold flash
- Dimension D, E do not include mold flash. Mold flash shall not exceed 0.127 mm per side measured at outer most extreme of plastic body.

 3.øP to have a maximum draft angle of 38.1 mm to

Q

S

5.49

6.05

3.ØP to have a maximum draft angle of 38.1 mm to the top of the part with a maximum hole diameter of 3.912 mm.

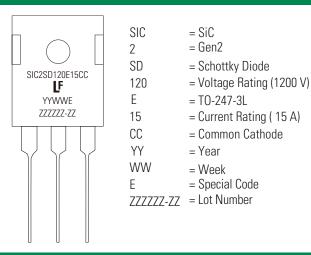
6.20

6.30



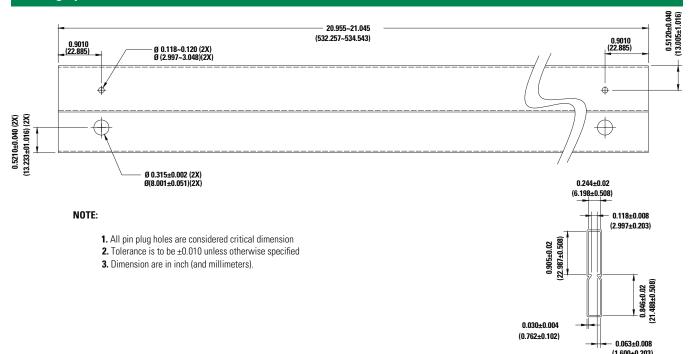
GEN2 SiC Schottky Diode LSIC2SD120E15CC, 1200 V, 15 A, T0-247-3L

Part Numbering and Marking System



Packing Options						
Part Number	Marking	Packing Mode	M.O.Q			
LSIC2SD120E15CC	SIC2SD120E15CC	Tube (30pcs)	450			

Packing Specification TO-247-3L



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SS3003CH-TL-E GA01SHT18 CRS10I30A(TE85L,QM MA4E2501L-1290 MBRB30H30CT-1G SB007-03C-TB-E SK32A-TP SK33B-TP
SK38B-TP NRVBM120LT1G NTE505 NTSB30U100CT-1G SS15E-TP VS-6CWQ10FNHM3 ACDBA1100LR-HF ACDBA1200-HF
ACDBA140-HF ACDBA2100-HF ACDBA3100-HF CDBQC0530L-HF CDBQC0240LR-HF ACDBA260LR-HF ACDBA1100-HF
SK310B-TP MA4E2502L-1246 MA4E2502H-1246 NRVBM120ET1G NSR01L30MXT5G NTE573 NTE6081 SB560 PMAD1108-LF
SD103ATW-TP